



SANYO Semiconductors

DATA SHEET

LA73051 — Monolithic Linear IC

3ch 75Ω Video Driver

Overview

This LA73051 is a 3ch 75Ω Video Driver IC. The LA73051 is ideal for use the video output driver such as VCR and DVD-player equipment.

Functions

- 6dB AMP+driver (3ch)

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		±7, +14	V
Allowable power dissipation	Pd max	Ta ≤ 80°C *	440	mW
Operating temperature	Topr		-20 to +80	°C
Storage temperature	Tstg		-55 to +150	°C

*: Mounted on a board : 114.3×76.1×1.6mm³ glass epoxy board.

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommending operation voltage	V _{CC}		±5 +9	V
Operating voltage range	V _{CC} op		±4.0 to ±5.5 +8 to +10	V

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LA73051

Electrical Characteristics at Ta = 25°C, VCC = ±5V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Current dissipation	ICC1	No signal	28.9	34.0	39.1	mA
Voltage gain	VG	VIN = 1Vp-p, f = 4.43MHz	5.7	6.2	6.7	dB
Frequency characteristics 1	VF1	VIN = 1Vp-p, f = 100k/5MHz	-1.0	0	1.0	dB
Frequency characteristics 2	VF2	VIN = 1Vp-p, f = 100k/27MHz		-25	-20	dB
Group delay	GD	f = 100k/4.43MHz		±10	±15	ns
Maximum output level	VO max	f = 1kHz, THD = 1%	3.0	4.0		Vp-p
Control voltage H level	VcntH	Pin 7 input voltage	2.5		VCC	V
Control voltage L level	VcntL	Pin 7 input voltage	0		1.0	V

Design guarantee items

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Video S/N	VG1V			-75	-70	dB
Differential Gain	DG	VIN = 1Vp-p, RAMP signal			1.0	%
Differential Phase	DP	VIN = 1Vp-p, RAMP signal			1.0	deg.
Mute attenuation	VMUTEV	VIN = 1Vp-p, f = 4.43MHz		-60	-55	dB
Cross-talk between channel	VCTKV	VIN = 1Vp-p, f = 4.43MHz		-60	-55	dB

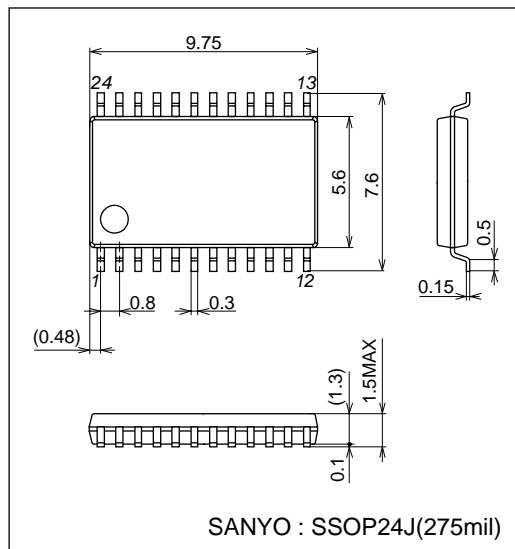
Truth Table

	Pin 7
H	THROUGH
L	MUTE

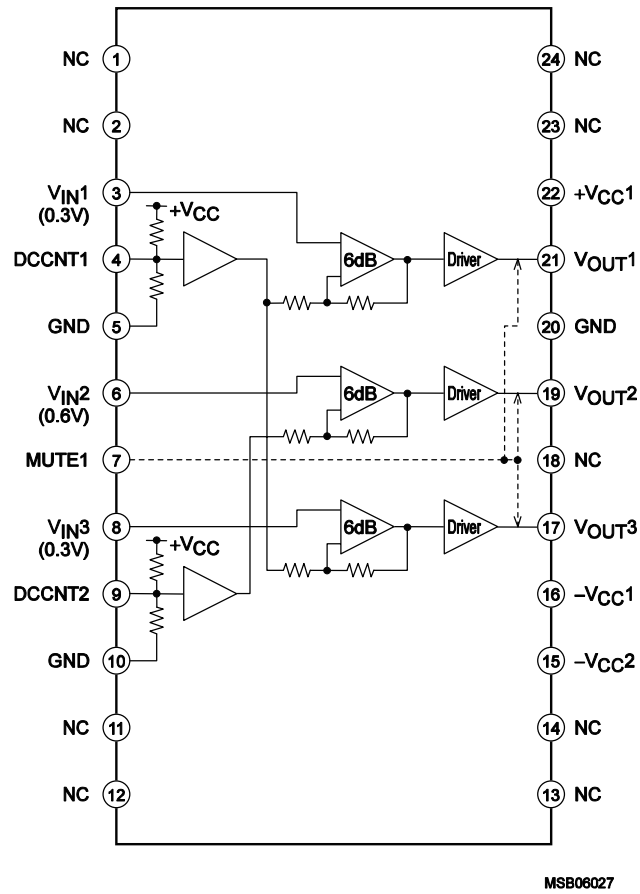
Package Dimensions

unit : mm

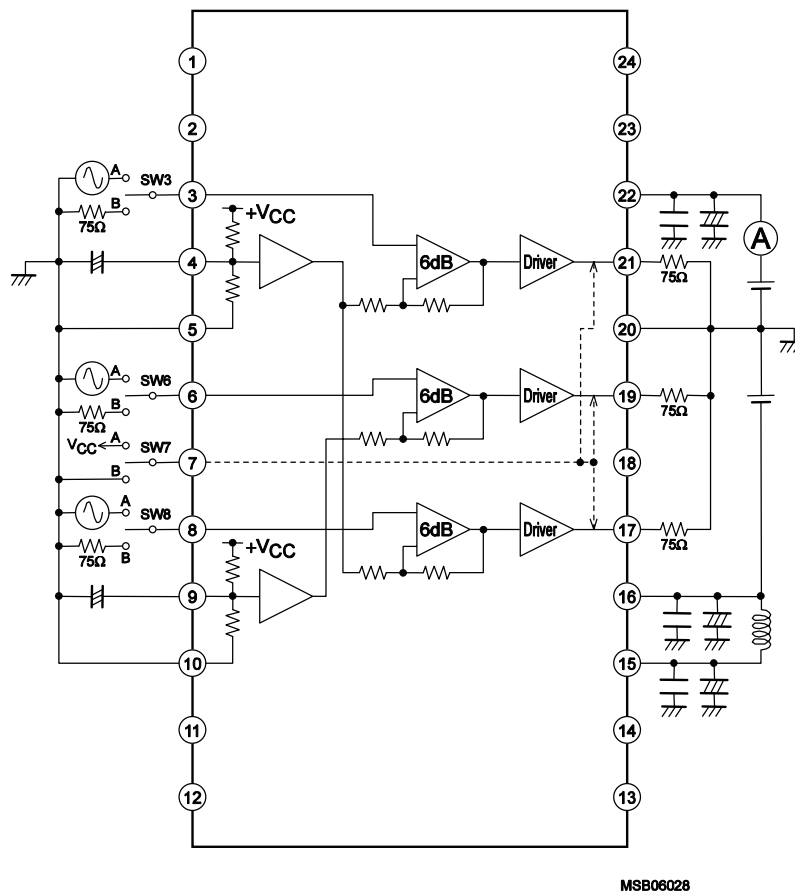
3315



Block Diagram



Test Circuit Diagram (Using \pm power supply)

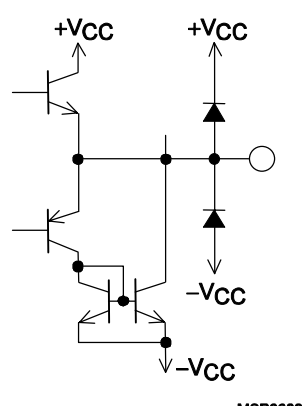


Pin Functions

Pin No.	Pin Name	Terminal Explanation	Equivalent Circuit
1 2 11 12 13 14 18 23 24	NC		
3 6 8	V _{IN1} V _{IN2} V _{IN3}	Input terminal. Non-bias. It is possible to use with being directly connected with DC. When DC coupling, it is necessary to add bias after the coupling.	
4 9	DCCNT1 DCCNT2	DC offset mode charge terminal between input and output. When a condenser is input at the position between pin 4 (DCCNT1) and GND, the operation of IC becomes the mode with 0.3VDC offset between input and output of 1, 3ch (pins 3 and 21, pins 8 and 17). Similarly when a condenser is input at the position between pin 9 (DCCNT2) and GND, it becomes the mode with 0.6VDC offset between input and output of 2ch (pins 6 and 19). And when pins 4, 9 and GND is shorted, it becomes the mode without DC offset between input and output.	
5 10 20	GND	Both ±power supply and +power supply are GND.	
7	MUTE1	Changeover terminal of Mute. When the Mute terminal is Low, it is Mute. When the terminal is Open, it is Low.	

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Pin No.	Pin Name	Terminal Explanation	Equivalent Circuit
15 16	-V _{CC}	-V _{CC} of using \pm power supply. Using +power supply, it is GND.	
17 19 21	V _{OUT3} V _{OUT2} V _{OUT1}	Output terminal. Using \pm power supply, in case of the mode with DC offset, it is possible to use without capacitor of output by setting pins 3, 8 to 0.3V-bias and by setting pin 6 to 0.6V-bias. And in case of the mode without DC offset, it is possible to use without capacitor of output by setting each input to zero-bias. When using +power supply, both of the modes needs coupling capacitor.	
22	+V _{CC}	Both \pm power supply and +power supply are +V _{CC} .	

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